NSN 5961-01-141-2675

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-141-2675 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.250 inches and 0.450 inches Overall Width: 1.050 inches **End Application:** 4920-01-084-7157 26916 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

NSN 5961-01-141-2675 Transistor - Page 2 of 2



Fiig:

A110a0